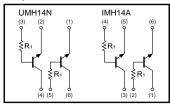
# General purpose (dual digital transistors) UMH14N/IMH14A

### Features

1) Two DTC144T chips in a UMT or SMT package.

# ●Equivalent circuit



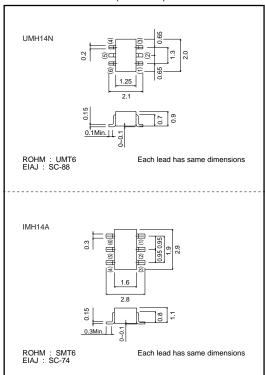
# ●Package, marking, and packaging specifications

| Туре                         | UMH14N | IMH14A |
|------------------------------|--------|--------|
| Package                      | UMT6   | SMT6   |
| Marking                      | H14    | H14    |
| Code                         | TR     | T108   |
| Basic ordering unit (pieces) | 3000   | 3000   |

# ●Absolute maximum ratings (Ta=25°C)

| Parameter                   |        | Symbol | Limits      | Unit |  |
|-----------------------------|--------|--------|-------------|------|--|
| Collector-base voltage      |        | Vсво   | 50          | V    |  |
| Collector-emitter voltage   |        | Vceo   | 50          | V    |  |
| Emitter-base voltage        |        | Vebo   | 5           | V    |  |
| Collector current           |        | lc     | 100         | mA   |  |
| Collector power dissipation | UMH14N | Pc     | 150(TOTAL)  | mW   |  |
|                             | IMH14A |        | 300(TOTAL)  |      |  |
| Junction temperature        |        | Tj     | 150         | °C   |  |
| Storage temperature         |        | Tstg   | -55 to +150 | °C   |  |

## ●External dimensions (Unit : mm)



# ●Electrical characteristics (Ta=25°C)

|                                      | •              |      |      |      |      |                               |
|--------------------------------------|----------------|------|------|------|------|-------------------------------|
| Parameter                            | Symbol         | Min. | Тур. | Max. | Unit | Conditions                    |
| Collector-base breakdown voltage     | ВУсво          | 50   | -    | -    | V    | Ic=50μA                       |
| Collector-emitter breakdown voltage  | BVceo          | 50   | -    | -    | V    | Ic=1mA                        |
| Emitter-base breakdown voltage       | ВУево          | 5    | -    | -    | V    | Iε=50μA                       |
| Collector cutoff current             | Ісво           | -    | -    | 0.5  | μА   | Vcb=50V                       |
| Emitter cutoff current               | Ієво           | -    | -    | 0.5  | μА   | V <sub>EB</sub> =4V           |
| Collector-emitter saturation voltage | VcE(sat)       | -    | -    | 0.3  | V    | Ic/I <sub>B</sub> =10mA/1mA   |
| DC current transfer ratio            | hfe            | 100  | 250  | 600  | -    | Vce/lc=5V/1mA                 |
| Transition frequency                 | f⊤             | _    | 250  | -    | MHz  | VcE=10V, IE= -5mA, f=100MHz * |
| Input resistance                     | R <sub>1</sub> | 32.9 | 47   | 61.1 | kΩ   | _                             |

<sup>\*</sup>Transition frequency of the device

## •Electrical characteristics curves

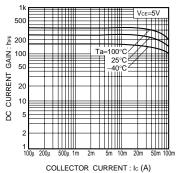


Fig.1 DC current gain vs. collector current

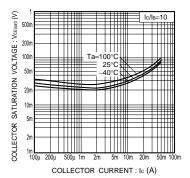


Fig.2 Collector-emitter saturation voltage vs. collector current

Rev.A

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